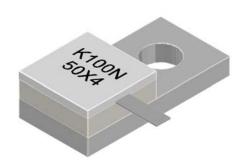




Half Flange Termination 100 Watts, 50Ω



Features:

- RoHS Compliant
- 100 Watts
- DC 3.0 GHz
- AIN Ceramic
- Non-Nichrome Resistive Element
- Low VSWR
- 100% Tested

Description

The K100N50X4 is high performance Aluminum Nitride (AIN) half flange termination intended as a cost competitive alternative to Beryllium Oxide (BeO). The termination is well suited to all cellular frequency bands such as; AMPS, GSM, DCS, PCS, PHS and UMTS. The high power handling makes the part ideal for terminating circulators, and for use in power combiners. The termination is also RoHS compliant!

General Specifications

Resistive Element Thick Film

Substrate AIN Ceramic

Cover Alumina Ceramic

Mounting Flange Copper, nickel plated per QC-N-290

Leads 99% pure silver (.006" thick)

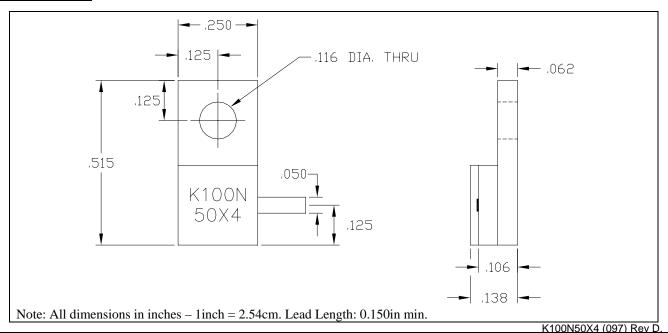
Tolerance is ± 0.010 ", unless otherwise specified. Designed to meet of exceed applicable portions of MIL-E-5400. All dimensions in inches.

Electrical Specifications

Resistance Value:50 Ohms, \pm 2%Power:100 WattsFrequency Range:DC - 3.0GHzV.S.W.R.1.25 : 1

Specification based on unit properly installed using suggested mounting instructions and a 50 ohm nominal impedance. Storage temperature is -20°C to 85 °C. Operating temperature is -55°C to 125°C (see chart for derating temperatures). **Specifications subject to change with out notice.**

Outline Drawing





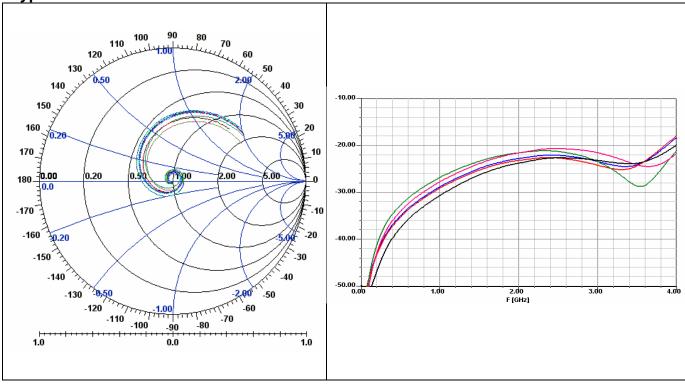
USA/Canada: (315) 432-8909 Toll Free: (800) 544-2414 Europe: +44 2392-232392

Model K100N50X4

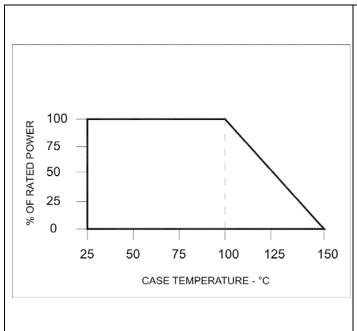




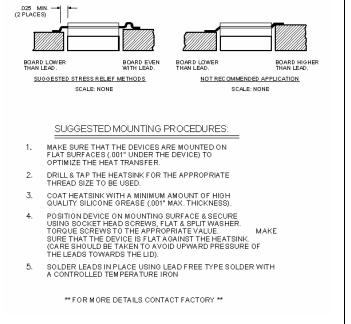
Typical Performance:



Power De-rating:



Mounting Footprint and Procedure:



K100N50X4 (097) Rev D

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